File View Edit Tools Window Help

Drafts
  BRS: 8 and
Pending
Active
  L1: (9275) 324/769,765,767,158.1.ccls.
  L2: (37) (((determin$4 or measur$4) near5 capac
  L3: (5) 1 and 2
  L4: (2069) 257/48,268,335.ccls.
  L5: (1) 2 and 4
  L6: (5798) 365/174,149.ccls.
  L7: (0) 2 and 6
Failed
Saved
  S1: (4) (("6069485") or ("5904490")).PN.
  S2: (2) ("5610104").PN.
  S3: (23044) transistor near2 structure
  S4: (11021) transistor adj structure
  S5: (6868) (transistor adj structure) and "257"
  S6: (118) (base with gate with drain) with insu
  S7: (13) ((transistor adj structure) and "257"/
  S8: (350) 324/769.ccls.
  S9: (4) 324/769.ccls. and (determin$4 near5 cap
  S10: (4) ("5304925" | "5493231" | "5493238" | "
  S11: (3) ("5194923" | "5268318" | "5600578").PN
  S12: (371) (determin$4 near5 capacitance) same
  S13: (14) ((determin$4 near5 capacitance) same

DB: US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TOB

Default operator: OR

Plurals

Highlight all hit terms initially

BRS form   IS&R form   Image   Text   HTML

	U	1	Document ID	Issue Dat	Pages	Title	Current OR	Current XR	Retrieval	Inventor	S	C	P	2	3	
1			US 3889188 A	19750610	6	Time zero determination of FET reliability	324/769			Trindade; David Charles						
2			US 4448400 A	19840515	22	Highly scalable dynamic RAM cell with self-sign	365/185.03	257/262; 257/300; 2		Harari; Eliyahou						
3			US 4520466 A	19850528	14	Dynamic random access memory	365/210			Mashiko; Koichiro						
4			US 4589003 A	19860513	9	Solid state image sensor comprising photo	257/258	257/262; 257/293; 2		Yamada; Hidetoshi et al.						
5			US 5365477 A	19941115	12	Dynamic random access memory device	365/174	257/110; 257/187; 2		Cooper, Jr.; James A. et al.						
6			US 5753946 A	19980519	18	Ferroelectric memory	257/295	257/E27.10 4; 257/E29		Naiki; Ihachi et al.						
7			US 5757204 A	19980526	16	Method and circuit for detecting boron ("B") i	324/769	324/765		Nayak; Deepak Kumar et al.						
8			US 5821766 A	19981013	15	Method and apparatus for measuring the metal	324/769	257/E21.53; 324/765		Kim; Sung-Ki et al.						
9			US 5835409 A	19981110	31	Compact page-erasable EEPROM non-volatile mem	365/185.15	257/209; 257/306; 2		Lambertson; Roy Tobler						

Hits   Details   HTML

Ready   NUM